

## IPM Photocoupler

### Product Description

The EMD2A481 fast speed photocoupler contains a LED and photo detector with built-in Schmitt trigger to provide logic-compatible waveforms, eliminating the need for additional wave shaping. The totem pole output eliminates the need for a pull up resistor and allows for direct drive Intelligent Power Module or gate drive. Minimized propagation delay difference between devices makes these optocouplers excellent solutions for improving inverter efficiency through reduced switching dead time.

### Applications

- IPM Interface Isolation
- Isolated IGBT/MOSFET Gate Drive
- AC and Brushless DC Motor Drives
- Industrial Inverters

### Features

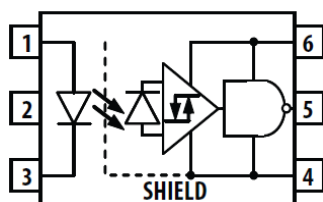
- Totem pole output inverter logic type
- Truth Table Guaranteed: VCC from 4.5V to 30V
- Performance Specified for Common IPM Applications Over Industrial Temperature Range.
- Short Maximum Propagation Delays
- Minimized Pulse Width Distortion (PWD)
- Very High Common Mode Rejection (CMR)
- Hysteresis
- Data rate: 5Mbps (typ.)

### Safety approved

- UL1577 recognized with 3750 Vrms for 1 minute for EMD2A481-SK and 5000 Vrms for 1 minute for EMD2A481-SL Certificate No. E529603
- IEC/EN/DIN EN 60747-5-5 Approved  
 $V_{IORM} = 891 V_{peak}$  for EMD2A481-SK  
 $V_{IORM} = 1140 V_{peak}$  for EMD2A481-SL  
 Certificate No. 40055846
- CQC approved: GB4943.1-2011  
 Certificate No. CQC22001358589

| SCHEMATIC | PIN DEFINITION   | PACKAGE |
|-----------|--|---------|
|           | 1. Anode<br>2. NC<br>3. Cathode<br>4. GND<br>5. VO<br>6. VCC |         |

## Connection Diagram



## Order Information

EMD2A481-00S###%FR1

|       |   |
|-------|---|
| EMD2A | Photo coupler product series  |
| 481   | Part Number   |
| 00    | Internal control Code   |
| S###  | SK06: LSOP-6 Package 7mm clearance<br>SL06: LSOP-6 Package 8mm clearance  |
| %     | E: RoHS & Halogen free package with VDE<br>N: RoHS & Halogen free package |
| F     | -40 to 110°C temperature rating   |
| R1    | Packing in Tape & Reel  |

## Order, Mark & Packing Information

| Package | Product ID                                 | Mark |   | Packing              |
|---------|--|------|---|----------------------|
| LSOP-6  | EMD2A481-00SK06EFR1<br>EMD2A481-00SL06EFR1 |      | E : ESMT<br>YY : Date code (Year)<br>WW : Date code (Week)<br>481 : Part Number<br>H : Internal Tracking Code | Tape & Reel<br>3Kpcs |
|         | EMD2A481-00SK06NFR1<br>EMD2A481-00SL06NFR1 |      | V : VDE ID Option   |                      |

## IEC/EN/DIN EN 60747-5-5 Insulation Characteristics

| Description   | Symbol        | EMD2A481-SK | EMD2A481-SL | Unit       |
|---|---------------|-------------|-------------|------------|
| Climatic Classification   | --            | 55/100/21   | 55/100/21   | --         |
| Pollution Degree (DIN VDE 0110/1.89)  | --            | 2           | 2           | --         |
| Maximum Working Insulation Voltage  | $V_{IORM}$    | 891         | 1140        | $V_{peak}$ |
| Input to Output Test Voltage, Method b (Note 1)<br>$V_{IORM} \times 1.875 = V_{PR}$ , 100% Production Test<br>With $t_m = 1$ sec, Partial discharge < 5pC | $V_{PR}$      | 1671        | 2137        | $V_{peak}$ |
| Input to Output Test Voltage, Method a (Note 1)<br>$V_{IORM} \times 1.6 = V_{PR}$ , 100% Production Test<br>With $t_m = 10$ sec, Partial discharge < 5pC  | $V_{PR}$      | 1426        | 1824        | $V_{peak}$ |
| Highest Allowable Overvoltage<br>(Transient Overvoltage $t_{ini} = 60$ sec)   | $V_{IOTM}$    | 6000        | 8000        | $V_{peak}$ |
| Safety-limiting values – maximum values allowed in the event of a failure   |               |             |             |            |
| Case Temperature  | $T_s$         | 175         | 175         | °C         |
| Input Current   | $I_s, INPUT$  | 150         | 150         | mA         |
| Output Power  | $P_s, OUTPUT$ | 600         | 600         | mW         |
| Insulation Resistance at $T_s$ , $V_{IO} = 500$ V   | $R_s$         | $>10^9$     | $>10^9$     | $\Omega$   |

Note 1 : Refer to the optocoupler section of the Isolation and Control Components Designer's Catalog, under Product Safety Regulations section, (IEC/EN/DIN EN 60747-5-5) for a detailed description of Method a and Method b partial discharge test profiles.

These optocouplers are suitable for "safe electrical isolation" only within the safety limit data.

Maintenance of the safety data shall be ensured by means of protective circuits. Surface mount classification is Class A accordance with CECC 00802.

## Insulation and Safety-Related Specifications

| Parameter  | Symbol | EMD2A  |        | Unit | Conditions  |
|--|--------|--------|--------|------|---|
|  |        | 481-SK | 481-SL |      |   |
| Minimum External Air Gap (External Clearance)    | L(101) | 7.0    | 8.0    | mm   | Measured from input terminals to output terminals, shortest distance through air.     |
| Minimum External Tracking (External Creepage)    | L(102) | 8.0    | 8.0    | mm   | Measured from input terminals to output terminals, shortest distance path along body. |
| Tracking Resistance (Comparative Tracking Index) | CTI    | $>175$ | $>175$ | V    | DIN IEC 112/VDE 0303 Part 1.  |

## Truth Table

| LED | V <sub>CC</sub> -V <sub>SS</sub> (Turn-ON) |
|-----|--|
| LED | OUT  |
| ON  | L  |
| OFF | H  |

Note 2: A 0.1μF bypass capacitor must be connected between Pin 4 and 6.

## Absolute Maximum Ratings (Ta = 25°C unless otherwise specified)

| Parameter                       | Symbol | Min  | Max | Unit |
|---------------------------------|--------|------|-----|------|
| Storage Temperature             | Tstg   | -55  | 125 | °C   |
| Operating Temperature           | Topr   | -40  | 110 | °C   |
| Output IC Junction Temperature  | TJ     | -    | 125 | °C   |
| Average Forward Input Current   | IF     | -    | 20  | mA   |
| Reverse Input Voltage           | VR     | -    | 5   | V    |
| Output Collector Current        | IO     |      | 50  | mA   |
| Supply Voltage                  | VCC    | 0    | 35  | V    |
| Output Collector Voltage        | VO     | -0.5 | Vcc | V    |
| Total Package Power Dissipation | PT     | -    | 145 | mW   |
| Lead Solder Temperature         | Tsol   | -    | 260 | °C   |

Note 3: A ceramic capacitor (0.1 μF) should be connected between pin 6 and pin 4 to stabilize the operation of a high gain linear amplifier. Otherwise, this Photocoupler may not switch properly. The bypass capacitor should be placed within 1 cm of each pin.

## Recommended Operation Condition

| Parameter                       | Symbol  | Min | Max | Unit |
|---------------------------------|---------|-----|-----|------|
| Operating Temperature           | TA      | -40 | 110 | °C   |
| Supply Voltage                  | VCC     | 4.5 | 30  | V    |
| Input Current (ON)<br>(Note 4)  | IF(ON)  | 1.6 | 5   | mA   |
| Input Voltage (OFF)<br>(Note 5) | VF(OFF) |     | 0.8 | V    |

Note 4: Detector requires a VCC of 4.5 V or higher for stable operation as output might be unstable if VCC is lower than 4.5 V. Be sure to check the power ON/OFF operation other than the supply current.

Note 5: The initial switching threshold is 1.6 mA or less. It is recommended that 2.2 mA be used to permit at least a 20% LED degradation guard band.

## Electrical Characteristics

All Typical values at  $T_A = 25^\circ\text{C}$ , unless otherwise specified; all minimum and maximum specifications are at recommended operating condition.

| Parameter                                     | Symbol                 | Min     | Typ      | Max  | Unit  | Test Condition                    |
|---|------------------------|---------|----------|------|-------|-----------------------------------|
| <b>Input Characteristics</b>                  |                        |         |          |      |       |                                   |
| Input Forward Voltage                         | VF                     | 1.6     | 2.0      | 2.4  | V     | IF=10mA                           |
| Input Forward Voltage Temperature Coefficient | $\Delta VF / \Delta T$ | -       | -1.237   | -    | mV/°C | IF=10mA                           |
| Input Reverse Voltage                         | BVR                    | 5       | -        | -    | V     | IR = 10 $\mu$ A                   |
| Input Threshold Current (Low to High)         | IFLH                   | -       | 0.25     | 1.5  | mA    | VCC = 30 V, VO < 5V               |
| Input Threshold Voltage (High to Low)         | VFHL                   | 0.8     | -        | -    | V     | VCC = 30 V, VO > 5V               |
| Input Capacitance (Note 6)                    | CIN                    | -       | 60       | -    | pF    | f = 1 MHz, VF = 0 V               |
| <b>Output Characteristics</b>                 |                        |         |          |      |       |                                   |
| High Level Supply Current                     | ICCH                   | -       | -        | 3.0  | mA    | VCC = 5.5 V, VF = 0V, IO = 0 mA   |
|   |                        |         | 1.9      | 3.0  |       | VCC = 30 V, VF = 0V, IO = 0 mA    |
| Low Level Supply Current                      | ICCL                   | -       | -        | 3.0  | mA    | VCC = 5.5 V, IF = 5 mA, IO = 0 mA |
|   |                        |         | 2.0      | 3.0  |       | VCC = 30 V, IF = 5 mA, IO = 0 mA  |
| High level output current (Note 7)            | IOH                    | -       | -        | -100 | mA    | VCC = 5.5V, VF = 0V, VO = GND     |
|   |                        | -       | -        | -200 |       | VCC = 20V, VF = 0V, VO = GND      |
| Low level output current (Note 7)             | IOL                    | 100     | -        | -    | mA    | VO = VCC = 5.5V, IF = 5mA         |
|   |                        | 200     | -        | -    |       | VO = VCC = 20V, IF = 5mA          |
| High level output voltage                     | VOH                    | VCC-0.5 | VCC-0.05 | -    | V     | IOL = -6.5mA                      |
| Low level output voltage                      | VOL                    | -       | 0.09     | 0.5  | V     | IOL = 6.5mA                       |

Note 6: Input capacitance is measured between pin 1 and pin 3.

Note 7: Duration of output short circuit time should not exceed 10  $\mu$ s.

## Switching Specification

All Typical values at  $T_A = 25^\circ\text{C}$ , unless otherwise specified; all minimum and maximum specifications are at recommended operating condition.

| Parameter   | Symbol                         | Min. | Typ. | Max. | Unit              | Test Condition   |
|---|--------------------------------|------|------|------|-------------------|--|
| Propagation Delay Time to Output High Level (Note 8)          | $t_{PLH}$                      | -    | 110  | 220  | ns                | $f = 10\text{kHz}$ ,<br>Duty Cycle = 50%<br>$I_F = 2\text{mA}$ ,<br>$V_{CC} = 30\text{V}$          |
| Propagation Delay Time to Output Low Level (Note 8)           | $t_{PHL}$                      | -    | 90   | 220  |                   |  |
| Pulse Width Distortion (Note 9)                               | PWD                            | -    | 20   | 120  |                   |  |
| Propagation Delay Difference Between Any Two Parts (Note 10)  | PDD<br>( $t_{PHL} - t_{PLH}$ ) | -200 | -    | +200 |                   |  |
| Output Rise Time (10 to 90%)                                  | $t_r$                          | -    | 6    | -    |                   |  |
| Output Fall Time (90 to 10%)                                  | $t_f$                          | -    | 7    | -    |                   |  |
| Common mode transient immunity at high level output (Note 11) | $ CM_H $                       | 20   | -    | -    | kV/ $\mu\text{s}$ | $V_F = 0\text{V}$ $V_{CC} = 5\text{V}$ ,<br>$T_A = 25^\circ\text{C}$ ,<br>$V_{CM} = 1.5\text{KV}$  |
| Common mode transient immunity at low level output (Note 11)  | $ CM_L $                       | 20   | -    | -    | kV/ $\mu\text{s}$ | $I_F = 4\text{mA}$ $V_{CC} = 5\text{V}$ ,<br>$T_A = 25^\circ\text{C}$ ,<br>$V_{CM} = 1.5\text{KV}$ |

Note 8: The  $t_{PLH}$  propagation delay is measured from the 50% point on the leading edge of the input pulse to the 1.3 V point on the leading edge of the output pulse. The  $t_{PHL}$  propagation delay is measured from the 50% point on the trailing edge of the input pulse to the 1.3 V point on the trailing edge of the output pulse.

Note 9 Pulse Width Distortion (PWD) is defined as  $|t_{PHL} - t_{PLH}|$  for any given device.

Note 10: The difference of  $t_{PLH}$  and  $t_{PHL}$  between any two devices under the same test condition.

Note 11:  $CM_H$  is the maximum slew rate of the common mode voltage that can be sustained with the output voltage in the logic high state,  $V_O > 2.0\text{V}$ .  $CM_L$  is the maximum slew rate of the common mode voltage that can be sustained with the output voltage in the logic low state,  $V_O < 0.8\text{V}$ .

Note: Equal value split resistors ( $R_{in}/2$ ) must be used at both ends of the LED.

## Isolation characteristic

All Typical values at  $T_A = 25^\circ\text{C}$  and  $V_{CC} - V_{SS} = 30\text{V}$ , unless otherwise specified; all minimum and maximum specifications are at recommended operating condition.

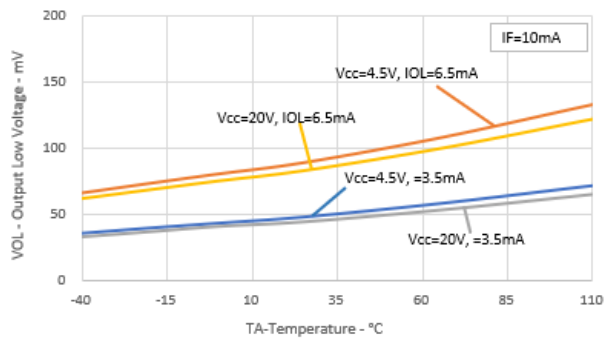
| Parameter                                       | Symbol    | Device      | Min. | Typ.      | Max. | Unit     | Test Condition  |
|---|-----------|-------------|------|-----------|------|----------|---|
| Withstand Insulation Test Voltage (Note 12, 13) | $V_{ISO}$ | EMD2A481-SK | 5000 | -         | -    | V        | $RH \leq 40\%-60\%$ ,<br>$t = 1\text{min}$ , $T_A = 25^\circ\text{C}$ |
|   |           | EMD2A481-SL |      |           |      |          |   |
| Input-Output Resistance (Note 12)               | $R_{I-O}$ | -           | -    | $10^{12}$ | -    | $\Omega$ | $V_{I-O} = 500\text{V DC}$  |

Note 12: Device is considered a two terminal device: pins 1, 2, 3 are shorted together and pins 4, 5, 6 are shorted together.

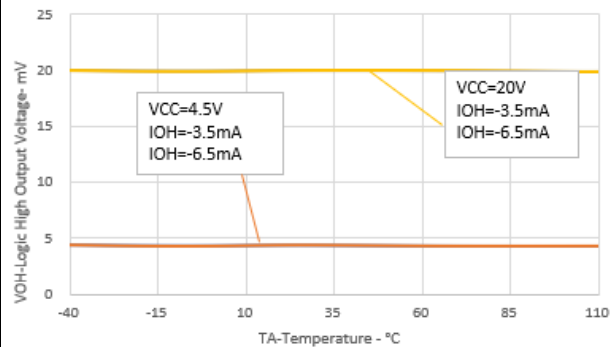
Note 13: According to UL1577, each photo coupler is tested by applying an insulation test voltage 6000VRMS for one second.

## Typical Performance Curves & Test Circuits

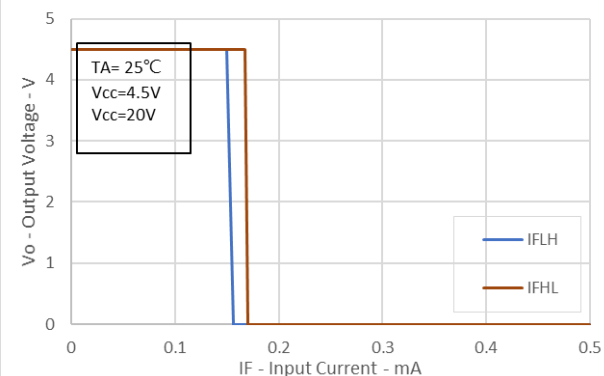
**Fig.1 VOL vs. Temperature**



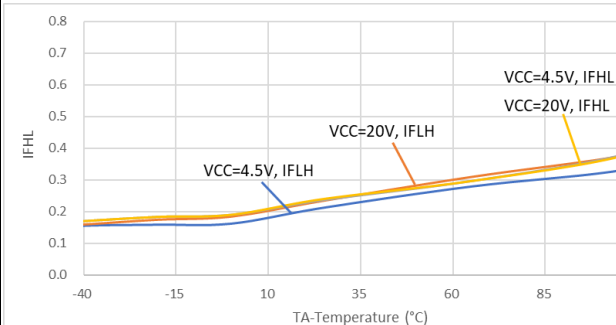
**Fig.2 VOH vs. Temperature**



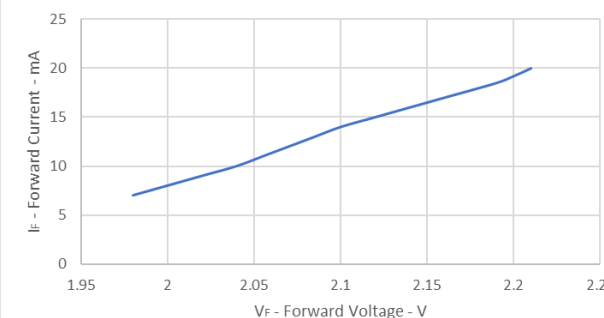
**Fig.3 IFLH vs. Hysteresis**



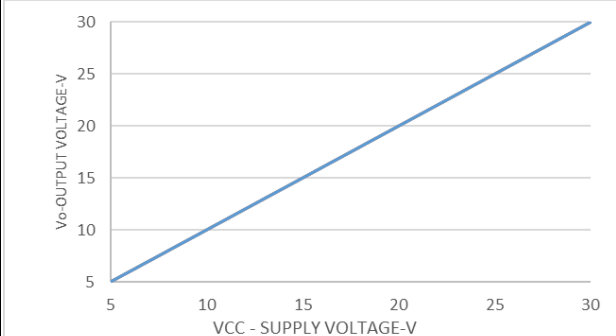
**Fig.4 IFH vs. Temperature**



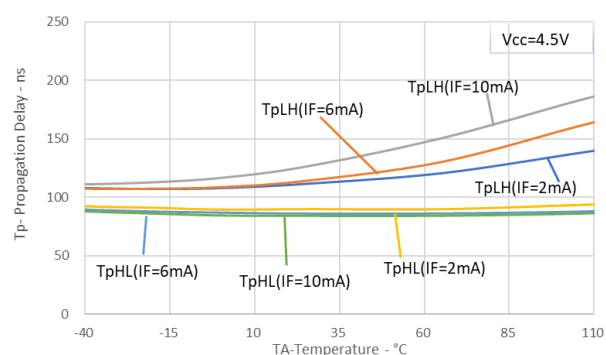
**Fig.5 Input Current vs. Forward Voltage**



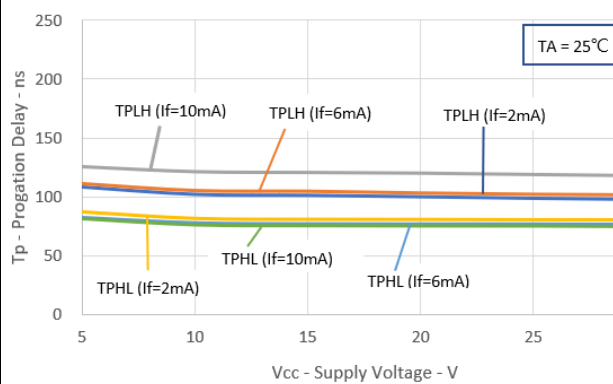
**Fig.6 Supply Voltage vs. Output Voltage**



**Fig.7 Propagation Delays vs. Temperature**

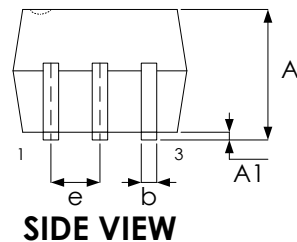
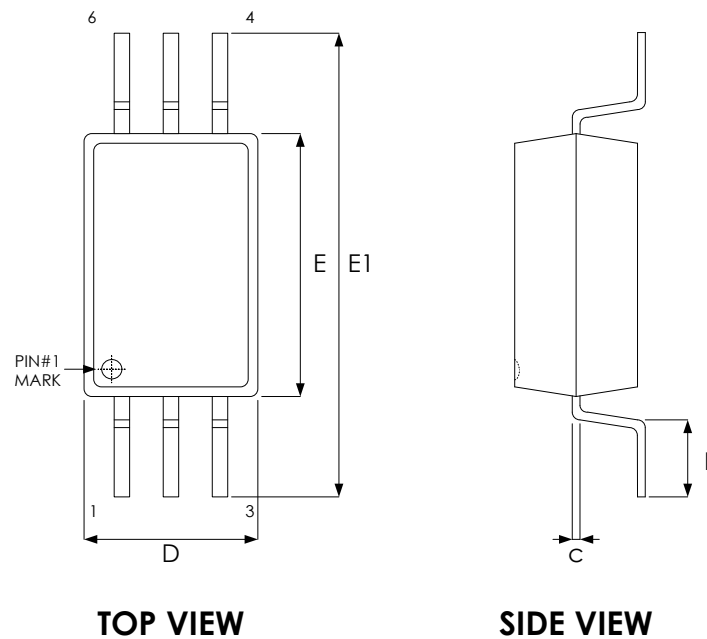


**Fig.8 Propagation Delays vs. Vcc**



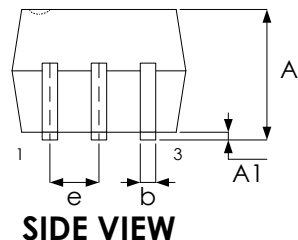
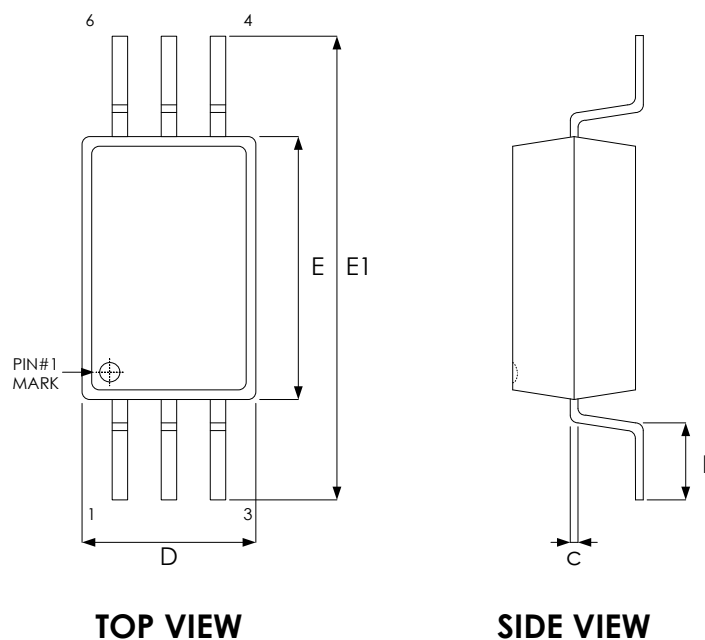


**Package Outline Drawing**  
**L-SOP 6L (277mil, 7mm clearance)**



| Symbol | Dimension in mm |       |
|--------|-----------------|-------|
|        | Min.            | Max.  |
| A      | 1.70            | 2.30  |
| A1     | 0.10            | 0.30  |
| b      | 0.30            | 0.50  |
| c      | 0.20            | 0.30  |
| D      | 4.20            | 4.80  |
| E      | 6.51            | 7.11  |
| E1     | 9.40            | 10.00 |
| e      | 1.27 BSC        |       |
| L      | 0.70            | 1.20  |

## Package Outline Drawing L-SOP 6L (277mil, 8mm clearance)



| Symbol | Dimension in mm |       |
|--------|-----------------|-------|
|        | Min.            | Max.  |
| A      | 1.70            | 2.30  |
| A1     | 0.10            | 0.30  |
| b      | 0.30            | 0.50  |
| c      | 0.20            | 0.30  |
| D      | 4.20            | 4.80  |
| E      | 6.51            | 7.11  |
| E1     | 11.20           | 11.80 |
| e      | 1.27 BSC        |       |
| L      | 0.50            | 1.00  |

**Revision History**

| Revision | Date       | Description  |
|----------|------------|--|
| 0.1      | 2023.02.17 | Preliminary version  |
| 0.2      | 2023.08.24 | Update:<br>Insulation Characteristics (Page3)<br>AMR unit (Page4)<br>Note7 (Page5)<br>  CMH     CML   Test condition (Page6) |
| 1.0      | 2024.03.05 | 1.Revise IOH/IOL spec<br>2.Update POD<br>3. Remove "preliminary" to V1.0   |

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